I$_2$ vapor-induced degradation of formamidinium lead iodide based perovskite solar cells under heat–light soaking conditions$^\dagger$

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Over the last years, the operational stability of perovskite solar cells has been significantly improved by compositional engineering, interface modification, and improved encapsulation techniques. However, irreversible degradation is still ubiquitously observed during the first 1000 hours of operation, particularly at elevated temperatures. In this work, we elucidate a major mechanism controlling this degradation. For that, formamidinium lead iodide-based perovskite solar cells were stressed under continuous 1 sun illumination at 80 °C in N$_2$ before extensive characterization of their microstructure and composition. The cell active area and hence the photocurrent are found to decrease with time due to the growth of porous PbI$_2$-rich regions. This degradation was observed to originate from a few seed points in the perovskite bulk rather than from the interfaces with the charge-selective layers or from the cell edges. I$_2$ vapor, first released at these defective points and then further released from the decomposition of the perovskite exposed to this vapor, controls the degradation process. Furthermore, this autocatalytic degradation process is shown to locally rupture the top electrode due to vapor pressure build-up. In addition to highlighting the detrimental influence of residual PbI$_2$, we show that such a degradation pathway can be alleviated by reducing the methylammonium and/or iodine content, providing a path to more stable perovskite solar cells.

Broader context
The promise offered by perovskite solar cells, i.e., high power conversion efficiency at low manufacturing costs, is starting to materialize. In their fresh, as-fabricated state, lab-scale (≈0.1 cm$^2$) perovskite solar cells have reached 24.2%, which is a greater efficiency than that of alternative polycrystalline thin-film photovoltaic technologies, and their combination with crystalline-Si or Cu(In,Ga)Se$_2$ in tandem devices surpasses the bottom cell performance. However, the key parameter that will eventually dictate the economic viability of perovskite-based photovoltaics (single-junction or tandem) is the long-term stability of perovskite solar cells. While significant improvements have been reported, perovskite solar cells usually degrade irreversibly during the first 1000 hours of operation in field-relevant temperatures. Moreover, the underlying mechanism of how the degradation initiates, propagates, and eventually leads to a catastrophic failure of the device remains largely elusive. In this work, we reveal a previously unknown but critical degradation mechanism of formamidinium-lead-iodide based perovskite solar cells operating at the maximum power point under combined heat and light illumination, close to real-world field conditions. We show that the degradation mechanism seems to be universal to state-of-the-art perovskite absorbers and device architectures, which calls for intensive investigations from the whole community to fully address this challenging issue.

Introduction
Metal halide perovskite [ABX$_3$, A = Cs$^+$, [CH$_3$NH$_3$]$^+$ (MA$^+$), [CH(NH$_2$)$_2$]$^+$ (FA$^+$); B = Pb, Sn; X = Cl, Br, I] absorber materials have been receiving increased attention due to their high-performance and potentially low-costs when implemented in thin film solar cells.$^1$ Although light-to-power conversion efficiencies have rapidly increased to a certified record of 24.2%$^3$ (≈0.1 cm$^2$, initial efficiency), perovskite solar cells still suffer from relatively poor operational stability compared to commercial photovoltaic technologies.$^3,4$
It is well documented that extrinsic parameters such as moisture,\(^2\) oxygen,\(^3\) light,\(^7\) temperature,\(^8\) electric fields,\(^9\) reverse bias,\(^10\) strain,\(^11\) etc. strongly influence the stability of perovskite solar cells. For example, MAPbI\(_3\)-based perovskite absorbers undergo severe degradation upon exposure to moisture and/or oxygen\(^{12-17}\) or moderate heat due to the volatile MA\(^+\) cation.\(^18\) Various studies have suggested that degradation mainly initiates from regions with higher defect densities such as grain boundaries,\(^{16,19,20}\) interfaces with charge selective layers\(^{21-23}\) and cell edges.\(^23\) As encapsulation techniques improve,\(^24-26\) other factors such as the device architecture,\(^14,27\) charge selective layers,\(^28,29\) interfaces,\(^17,30\) electrodes,\(^31,32\) and perovskite quality/composition\(^33-35\) eventually start to control the device stability. Among the various intrinsic degradation mechanisms proposed for MAPbI\(_3\) films, those induced by I\(_2\) vapor released by the decomposition of the absorber itself have been the subject of several studies.\(^18,36-38\) Particularly, Wang et al.\(^36\) demonstrated that MAPbI\(_3\) degrades quickly when intentionally exposed to I\(_2\). In devices, Ag metal electrodes were found to oxidize when in contact with such vapor (even when encapsulated), which also led to a loss in performance.\(^39-41\)

Engineering the perovskite absorber by switching to more robust and efficient FAPbI\(_3\)-based compositions,\(^42,43\) and introducing inorganic cations/anions (such as Cs, Rb, and Br),\(^33,44-47\) large organic 2D cations,\(^41,48\) or molecular additives\(^49,50\) has significantly improved the operational stability of perovskite solar cells. Thanks to these modifications, several groups have shown that perovskite solar cells can retain more than 90% of their initial performance after long-term (500–1000 hours) stability tests.\(^26,29,44,51,52\) Although the stress conditions (illumination source, atmosphere, temperature, time, etc.) may differ between studies, and some of the degradation can be recovered by leaving the cells in the dark,\(^53,54\) these devices typically exhibit irreversible degradation, as summarized in the ESI,† Table S1. But little information is provided on how the degradation initiates, propagates, and eventually leads to a catastrophic failure of the device. In other words, the mechanisms that control this irreversible degradation in solar cells remain unknown.

In this work, we attempt to elucidate these underlying mechanisms. Here, un-encapsulated (FA,MA)PbI\(_3\)(Br),\(_3\)-based perovskite solar cells were continuously operated at the maximum power point at 80 °C in N\(_2\) and then characterized in detail. The results highlight the deleterious role of I\(_2\), which is generated during cell degradation and acts as a source of further degradation. At the microstructural level, this I\(_2\)-driven degradation manifests itself in the form of circular regions that are rich in PbI\(_2\) and exhibit a porous morphology. These circular regions nucleate from a small number of seeds that appear during heat–light soaking testing and grow with time during operation at 80 °C. We demonstrate that the degradation pattern is independent of the perovskite composition and preparation method, charge selective layers, and transparent conducting oxide, suggesting the generality of the I\(_2\) vapor-assisted degradation mechanism.

### Accelerated degradation testing

The perovskite solar cells investigated here are assessed in a substrate configuration\(^55\) and feature a planar stack of soda lime glass substrate/indium tin oxide (ITO)/poly[bis(4-phenyl)-[2,4,6-trimethylphenyl]amine] (PTAA)/perovskite/phenyl-c61-butyric acid methyl ester (PCBM)/ZnO nanoparticles/alumindoped zinc oxide (AZO)/Ni-Al grid/MgF\(_2\) anti-reflection coating. The perovskite absorbers were prepared by a partial ion-exchange (PIE) approach,\(^47\) where a MABr solution was spin coated onto a crystallized FAPbI\(_3\) absorber to form a mixed cation lead mixed halide perovskite absorber. The absorber composition prepared by PIE is referred to as FAPbI\(_3\) (starting absorber):MABr (exchanged precursor, concentration). Compared to the anti-solvent method,\(^56\) the hybrid method allows the growth of a high-quality perovskite absorber on very rough substrates, such as micrometer-sized pyramids of a textured Si wafer\(^41\) and wavy flexible polymer foil.\(^57\) The second post-deposition treatment (MABr in this case) introduces bandgap grading and/or surface passivation, facilitating charge extraction and reducing interfacial recombination.\(^37\) This additional post-deposition treatment has been implemented in solution processed perovskite solar cells, and significantly improved the Voc as demonstrated by several groups.\(^58,59\) Moreover, the PIE method is compatible with novel post-deposition treatments, such as those including guanidinium bromide,\(^60\) n-hexyl trimethyl ammonium bromide,\(^61\) and phenethylammonium iodide,\(^62\) to further improve the device performance.

As shown in Fig. 1a, accelerated heat–light soaking (HLS) stability tests were performed on these devices until significant degradation could be observed. Fig. 1b displays a cross-sectional scanning electron microscopy (SEM) image of the as-prepared perovskite solar cell investigated in this study. The cell was first tested under maximum power point (MPP) conditions for 1000 hours at 60 °C under continuous 1 sun illumination intensity in a 500 mbar N\(_2\) atmosphere, as reported in previous work.\(^57\) The cell was subjected to full area illumination, i.e. the cell edges, where the perovskite absorber is exposed to the environment, were also illuminated. Using the same device, illumination, and atmospheric conditions, the stress temperature was then increased to 80 °C to accelerate the degradation process. Fig. 1c presents the normalized power output, Voc, Jsc and FF of a perovskite cell during 320 hours of MPP operation at 80 °C under continuous 1 sun illumination. As can be seen from Fig. 1c, the catastrophic degradation regime is mainly dominated by a lower short-circuit current density (Jsc) and a slightly decreased fill factor (FF), while the open-circuit voltage (Voc) even increased initially and then remained almost constant. The HLS experiment was stopped at around 320 h to avoid the complete degradation of the device and enable further characterization to understand the underlying degradation mechanisms.

To accurately evaluate the dominant degradation losses, the photovoltaic performance of the FAPbI\(_3\):MABr (10 mg ml\(^{-1}\)) perovskite device was measured immediately after HLS under standard test conditions (STC: 100 mW cm\(^{-2}\), simulated AM 1.5G, 25 °C). As shown in Fig. 1d, the cell started from a steady-state efficiency of 13.6%, which dropped to 12.7% after 1000 hours at 60 °C in N\(_2\). After a further 320 hours of HLS at 80 °C, the cell delivered a stabilized efficiency of 4.1%, with this value increasing to 4.7% after 10 months of subsequent storage in a vacuum (see the MPP measurements in the ESI,† Fig. S1a).
Fig. 1e compares the external quantum efficiency (EQE) measured before degradation, and after 1000 hours at 60 °C, 320 hours at 80 °C and vacuum storage for 10 months (the last two curves were acquired at the position of a remaining dark brown area of the cell). The EQE after degradation did not decrease significantly compared to before, which indicates that the measured $J_{SC}$ loss mainly originates from the reduction of the cell active area as shown in the photographs (Fig. 1f–h). Indeed, two distinct areas can be observed in Fig. 1h: an inactive yellow area and an active dark brown area, as confirmed by electroluminescence imaging (Fig. 1i). To verify that the decrease in $J_{SC}$ indeed stems from the loss in the active area, the $J_{SC}$ of the cell after 320 hours of HLS was re-calculated using only the brown region area. As shown in the ESI,† Table S2, the re-calculated $J_{SC}$ is close to the value calculated from the EQE, confirming this hypothesis.
Steady-state photoluminescence (PL) measured in the brown area shows a PL peak position of 781 nm (corresponding to an optical bandgap of 1.59 eV), which indicates that the bandgap of this region did not change throughout HLS at 60 °C and 80 °C (ESI† Fig. S2). From Fig. 1f–h, the inactive regions appear to originate from yellow spots that appeared during HLS at 60 °C (see e.g. the red arrow in Fig. 1g) and then these domains grew outwards during HLS at 80 °C. Intriguingly, the majority of the cell edges did not act as degradation centers even though the perovskite is directly exposed to the N2 atmosphere at the scribe lines. In that regard, Alberti et al. demonstrated that exposure to an N2 atmosphere can recover lattice disorder (in MAPbI3) and stabilize undercoordinated Pb2+ and MA+ cations through weak electrostatic interactions.63

Chemistry, crystallography, and microstructure of the degraded cells

To gain further insights into the initiation and propagation of the degradation, X-ray diffraction (XRD) measurements were performed to examine the crystallography of the cell stressed at 80 °C (referred to as “after HLS” hereafter, Fig. 2a). The initial XRD pattern of the device before any long-term stability test shows that the absorber is mainly composed of α-FAPbI3:MABr (10 mg ml⁻¹) without any detectable trace of δ-FAPbI3. After HLS, the intensity of the α-FAPbI3:MABr (10 mg ml⁻¹) main peak decreases significantly, while the dominant phase becomes PbI2. A small peak of metallic Pb is detected at 31.28°. These results complement the previous EL and PL measurements: yellow areas are composed mainly of PbI2, while the dark brown area is still α-FAPbI3:MABr (10 mg ml⁻¹). Interestingly, a small δ-FAPbI3 peak emerges after HLS. Unlike the MAPbI3 absorber, where the perovskite directly decomposes into PbI2, the degradation pathway of α-FAPbI3 appears more complex due to this phase transition. As shown in the ESI†, Fig. S3, bare layers of α-FAPbI3 on glass tend to transform into δ-FAPbI3 instead of directly decomposing into PbI2 when stored in ambient air, as also observed in the literature.36,42,65 The phase transition between α- and δ-FAPbI3 is reversible by re-annealing the absorber in the air (ESI† Fig. S4).

To find out the exact degradation pathway of α-FAPbI3-based solar cells during HLS, i.e. whether α-FAPbI3:MABr (10 mg ml⁻¹)-based absorbers directly decompose into PbI2 or first undergo a phase transition and then decompose into PbI2, full solar cells were analyzed by variable temperature X-ray diffraction. As observed in Fig. 2b, α-FAPbI3:MABr (10 mg ml⁻¹) directly decomposed into PbI2 without generating detectable δ-FAPbI3 during 42 hours of in situ measurements at 80 °C. To facilitate the degradation process, the temperature was further raised to 100 °C in another measurement. As shown in Fig. 2c, the first 10 hours of measurements exhibit a similar degradation pathway to that of the cell measured at 80 °C. However, δ-FAPbI3 was detected after 13 hours at 100 °C and the XRD peak intensity increased gradually with time. These results indicate that α-FAPbI3:MABr
(10 mg ml⁻¹) directly decomposed into PbI₂ and the δ-FAPbI₃ yellow perovskite phase formed at a later stage. The formation of δ-FAPbI₃ is likely to stem from a reaction of PbI₂ with gaseous species (FAI, FA, I₂, etc.) generated during the decomposition of the perovskite and/or mobile ions (FA⁺, I⁻, etc.) that may be already present in the perovskite absorber. Concerning the latter case, Yuan et al. demonstrated reversible conversion between MAPbI₃ and PbI₂ by migrating MA⁺ and I⁻ ions under an electrical bias at elevated temperature. To find out the main degradation of the perovskite.

Furthermore, it is worth noting that the decrease of the perovskite films: only an increase in PbI₂ intensity is observed, even after maintaining the films for 48 h at 100 °C (in an N₂ flow). This discrepancy between the bare layers and full devices can be explained as follows. In a bare film configuration, gaseous species released by the perovskite during its degradation escape and do not react with PbI₂ to form the δ-FAPbI₃ phase. The story changes in full devices, where the contact layers hinder the release of these gaseous species to the atmosphere, hence favoring their reaction with PbI₂ to form the δ-FAPbI₃ phase. Furthermore, it is worth noting that the decrease of the perovskite main peak intensity was slower in the case of a bare film compared to a full device, suggesting that the presence (and stagnation) of gaseous species (once generated) could accelerate the degradation of the perovskite.

The formation of δ-FAPbI₃ after long-term light-soaking (1000 hours at 60 °C) is also observed in pure FAPbI₃ solar cells as shown in the ESI† Fig. S5, unlike in the full devices, no δ-FAPbI₃ is detected during HLS treatment of the bare perovskite films: only an increase in PbI₂ intensity is observed, even after maintaining the films for 48 h at 100 °C (in an N₂ flow). The formation of δ-FAPbI₃ formation route, the XRD data of full devices was compared to that of a bare perovskite absorber (FAPbI₃:MABr (10 mg ml⁻¹)). As shown in the ESI† Fig. S5, unlike in the full devices, no δ-FAPbI₃ is detected during HLS treatment of the bare perovskite films: only an increase in PbI₂ intensity is observed, even after maintaining the films for 48 h at 100 °C (in an N₂ flow). This discrepancy between the bare layers and full devices can be explained as follows. In a bare film configuration, gaseous species released by the perovskite during its degradation escape and do not react with PbI₂ to form the δ-FAPbI₃ phase. The story changes in full devices, where the contact layers hinder the release of these gaseous species to the atmosphere, hence favoring their reaction with PbI₂ to form the δ-FAPbI₃ phase. Furthermore, it is worth noting that the decrease of the perovskite main peak intensity was slower in the case of a bare film compared to a full device, suggesting that the presence (and stagnation) of gaseous species (once generated) could accelerate the degradation of the perovskite.

The formation of δ-FAPbI₃ after long-term light-soaking (1000 hours at 60 °C) is also observed in pure FAPbI₃ solar cells as shown in the ESI† Fig. S5. Previously, it was frequently reported that the α-FAPbI₃ phase tends to transform into δ-FAPbI₃ even after storage at room temperature. However, we observe that once α-FAPbI₃ is incorporated into a full device covered with a TCO, this absorber remains stable for 1000 hours under 1 sun light intensity at 60 °C (ESI† Fig. S6) and long-term storage in a vacuum at room temperature. As shown in the ESI† Fig. S7, δ-FAPbI₃ was not observed in a α-FAPbI₃ solar cell after 460 days of storage in a vacuum.

Fig. 3 shows cross-sectional SEM images taken across the brown/yellow transition area of the full devices after 320 hours HLS at the MPP. Three distinct regions can be observed and are classified into a degraded area (left), a transition area (middle) and an intact area (right). Higher magnification SEM images (Fig. 3b–d) show that the compact morphology with large grains of the absorber is maintained in the intact area (as in Fig. 1b), while the degraded area exhibits a porous morphology indicative of a loss of material from the absorber. The transition area features voids of different sizes primarily within the absorber bulk instead of its interfaces. In that regard, the degradation mechanism of the FAPbI₃:MABr (10 mg ml⁻¹) cells investigated here at 80 °C in an N₂ atmosphere differs from previous reports: the perovskite bulk rather than the perovskite/charge transport layer interfaces seems to degrade first. The AZO layer appears broken and bent at certain positions in the degraded region away from the transition area (Fig. 3e). Cross-sectional SEM images (ESI† Fig. S8) of perovskite cells after variable temperature storage in a vacuum at room temperature exhibit a similar microstructure. A large number of holes are observed in the absorber and the AZO is locally ruptured.

Extracting a thin lamella of material using the conventional focused ion beam (FIB) method and performing a scanning transmission electron microscopy (STEM) energy-dispersive X-ray spectroscopy (EDX) analysis of one of the cracked regions (Fig. 4a–c) reveals that Pb, I, and Br were expelled from the absorber and redeposited on the crack top surface (Fig. 4d).

Fig. 3 Microstructural analysis. (a) Low magnification cross-sectional SEM image spanning from the yellow to the brown areas of the perovskite cell after 320 hours HLS at 80 °C. Three different morphologies can be observed, which are assigned to the degraded area, transition area, and intact area. (b–d) High magnification cross-sectional SEM images of the degraded (b), transition (c), and intact areas (d). (e) Microstructure of a degraded area that features a broken top electrode.
This transport of material is indicative of pressure building up in the absorber, a pressure that eventually leads to a rupture of the top electrode. Regions richer in Pb suggestive of metallic Pb are marked by arrowheads at the crack edge. Other Pb-rich clusters are also observed (Fig. 4e) inside the cell. These are surrounded by PbI₂ regions, in accordance with the XRD data shown in Fig. 2a, and large voids, in line with the SEM data presented in Fig. 3d (note that the fraction of voids is higher in the FIB-prepared cross-section due to preferential sputtering of perovskite regions not protected by other layers in the line of sight of the gallium ions). On the other hand, a FIB cross-section extracted from the non-degraded dark brown area exhibited a more compact microstructure and a distribution of elements as anticipated for a functional perovskite (Fig. 4f, the presence of In and Mg within the absorber is an artifact of the quantification procedure). This preserved microstructure is in accordance with the SEM data shown in Fig. 1b and 3d and the EL data of Fig. 1i.

To assess which compounds are more likely to escape from the perovskite layer and lead to the top electrode fracture, a thermogravimetric analysis/mass spectrometry (TGA-MS) measurement was performed by heating a powder of the same FAPbI₃:0.1MABr perovskite material up to 400 °C. As presented in the ESI,† I₂ and CH₃I are the main gas products generated during the decomposition of the perovskite powder. The generation of other gaseous species such as NH₃ and HI molecules cannot be excluded, but their concentration was outside the detection range of the instrument. Various studies have shown that I₂ vapor can be released from both perovskite films and full solar cells under illumination. For instance, using time-resolved mass spectrometry, Song et al. and Juarez-Perez et al. independently confirmed that I₂ vapor is one of the main volatile compounds when degrading perovskites at a temperature between 60 and 80 °C under illumination (the conditions used here).
To summarize the XRD, electron microscopy and TGA-MS findings so far, the \( \gamma \)-FAPbI\(_3\):MABr (10 mg m\(^{-1}\)) perovskite layer decomposed mainly to PbI\(_2\) but also to \( \delta \)-FAPbI\(_3\) and Pb as minor decomposition products. This then left large PbI\(_2\)-rich regions exhibiting a porous microstructure, and cracks in the top electrode. These effects were attributed to the volatilization of gaseous products, mainly I\(_2\) and other organic compounds, directly from the perovskite bulk. Importantly, I\(_2\) has been shown to degrade the perovskite layer to PbI\(_2\) in a previous report.\(^{71}\)

### Degradation mechanism study

The degradation process observed here differs from moisture- and/or oxygen-induced degradation mechanisms as reported previously\(^{5,6,20,37}\) and highlighted in the ESI,\(^{†}\) Fig. S10, which investigates the degradation of cells in ambient air. The data presented above tend to indicate that the release of I\(_2\) vapor from the cell, an effect that has been shown to decompose perovskite layers,\(^{26}\) may be the main cause of degradation during these HLS experiments. As explained below, the release of I\(_2\) vapor from the decomposition of the absorber may trigger further decomposition of the neighboring perovskite regions.

Now we attempt to probe the factors that trigger the release of I\(_2\) in the first place. PbI\(_2\) and perovskite (FAPbI\(_3\):MABr (10 mg m\(^{-1}\)) films (deposited on PTAA/ITO/glass substrates) were illuminated and heated on a hotplate inside an N\(_2\)-filled glovebox (water and oxygen content below 0.1 ppm, \(\sim 0.1\) sun illumination intensity, 80 °C, ESI,\(^{†}\) Fig. S11a). PbI\(_2\) was found to be more prone to degradation than the perovskite absorber under these conditions as shown in the XRD patterns of Fig. 5a and b. The PbI\(_2\)(011) peak shifted towards higher angles, indicating a lattice contraction. The (111) and (002) peaks of metallic Pb (31.28° and 36.27°, respectively) appeared and increased with time, indicating a loss of iodine. Control XRD experiments performed in the dark indicate that illumination, even under a 0.1 sun intensity,\(^{†}\) indicates that illumination, even under a 0.1 sun intensity,\(^{†}\) may be the main driver for iodine loss, not temperature.\(^{5,6,20,37}\)

First principles calculations\(^{77}\) have shown that the defect chemistry of I\(_2\) molecule.\(^{77}\) Both paths (loss of an organic molecule and loss of a interstitial halogen (such as I\(_i\)) defects (Fig. 6a). Following a trap filling reaction, the defect I\(_i\) \(_i\) pair could react to form an I\(_2\) molecule.\(^{77}\) Both paths (loss of an organic molecule and loss of a neutral iodine atom) could contribute to initial I\(_2\) generation under heat/light soaking conditions. In addition, the presence of PbI\(_x\), either induced by the migration/loss of ions such as MA\(^+\) (Fig. 5f) or excess PbI\(_2\) (Fig. 2a) already present in the as-deposited state, may accelerate the cell degradation by dissociating slowly into Pb and the deleterious I\(_2\) under illumination.

X-ray photoelectron spectroscopy (XPS) was performed to examine the compositional changes upon illumination (Fig. 5c and d). A small Pb\(^0\) peak of constant intensity is observed on the top surface in all the PbI\(_2\) films (irrespective of the HLS treatment). On the other hand, such a peak is not observed for the as-prepared and stressed perovskite films under the same conditions. While the Ar\(^+\) plasma used to reveal the bulk composition of the layers artificially damaged both PbI\(_2\) and the perovskite, the magnitude of the Pb\(^0\) peak in the bulk increases with the HLS duration in both cases. This difference tends to indicate that the HLS treatment modifies mainly the perovskite interior rather than its top surface, which is consistent with previous findings at the device level (SEM in Fig. 3). To complement this data, time-of-flight secondary ion mass spectrometry (ToF-SIMS) depth profiling was performed using a Cs\(^+\) sputter beam and the positive secondary ion signals are shown in Fig. 5e and f. The [CsPbI\(_2\)]\(^+\) signal, which was used to probe the variation in concentration of PbI\(_2\), decreased in the PbI\(_2\) samples during HLS (Fig. 5e), which is in accordance with partial decomposition of PbI\(_2\) to Pb and I\(_2\) under illumination. Concerning the perovskite layers, the [CsPbI\(_3\)]\(^+\) signal increased while the MA\(^+\) intensity decreased after 10 hours of HLS (Fig. 5f). Meanwhile, the FA\(^+\), I\(^-\), Pb\(^+\), C\(^+\), and [In\(_2\)O\(_3\)]\(^+\) signals remained almost constant.

Overall, these XRD, XPS and ToF-SIMS results indicate that the perovskite degradation initiated from the perovskite bulk, in agreement with microstructural observations. Particularly, the loss of MA\(^+\) from the perovskite absorber under HLS followed by subsequent perovskite decomposition could be a critical step to trigger the release of I\(_2\) vapor. On the basis of previous literature, other routes for I\(_2\) vapor generation are also possible. Kim et al.\(^{69}\) observed that light excitation enhances by several orders of magnitude the halide conductivity due to an increased population of halide vacancies. Photogenerated holes react with the iodine sub-lattice, which pushes neutral iodine into the nearby interstitial lattice.\(^{69}\) Recent ab initio molecular dynamics also showed the formation of neutral iodine interstitials via a trap filling reaction, and two filled traps can further form an I\(_2\) molecule.\(^{72}\) Both paths (loss of an organic molecule and loss of a neutral iodine atom) could contribute to initial I\(_2\) generation under heat/light soaking conditions. In addition, the presence of PbI\(_x\), either induced by the migration/loss of ions such as MA\(^+\) (Fig. 5f) or excess PbI\(_2\) (Fig. 2a) already present in the as-deposited state, may accelerate the cell degradation by dissociating slowly into Pb and the deleterious I\(_2\) under illumination.

Fig. 6 schematically illustrates the proposed degradation pathway inferred from the experimental data presented above. An I\(_2\) vapor-triggered and -assisted degradation mechanism is proposed to account for the degradation behavior under HLS. First principles calculations\(^{77}\) have shown that the defect chemistry in lead halide perovskites is dominated by lead vacancies (V\(_{\text{Pb}}\)) and interstitial halogen (such as I\(_i\)) defects (Fig. 6a). Following a trap filling reaction, the defect I\(_i\)/I\(_i\) pair could react to form an I\(_2\) molecule in the bulk under illumination.\(^{77}\) Additionally, the loss of volatile MA\(^+\) could result in local decomposition of the perovskite associated with a release of I\(_2\) vapor (Fig. 6b). The I\(_2\) would then further deteriorate the neighboring perovskite and induce the formation of more I\(_2\) vapor and PbI\(_2\) (Fig. 6c). This process is
autocatalytic and dominates the degradation of the perovskite in these HLS conditions. Meanwhile, the formation of PbI\textsubscript{2}-rich regions, which could then decompose into metallic Pb and I\textsubscript{2} vapor under illumination, further accelerates the degradation process. In addition, PbI\textsubscript{2} can react in some places with the generated gas to form $\delta$-FAPbI\textsubscript{3}, as observed by XRD. The release of gaseous degradation products gives rise to a pressure buildup inside the perovskite (Fig. 6d). Once the pressure is high enough, the top electrode eventually breaks (Fig. 6e). It seems that degradation nucleates from only a few points from the experimental observations. But once it starts, it proceeds autocatalytically as long as I\textsubscript{2} remains trapped in the cell, which highlights the influence of the permeability of the top electrode on the degradation mechanism reported here.

**Compositional dependent stability**

From the above discussion, it is desirable to reduce the iodine and residual PbI\textsubscript{2} content in order to achieve better operational
stability at high temperature. As shown in Fig. 7, the starting point of the catastrophic degradation was retarded to around 250 hours at 80 °C by increasing the Br content in the FAPbI$_3$:MABr (20 mg ml$^{-1}$) absorber. As before, circular degradation patterns were observed (Fig. 7a–c). The $J$–$V$ curves and EQE spectra (ESI,† Fig. S13 and S14) of the cell measured after HLS confirm that the degradation was mainly due to a loss of active area. The top-view morphology of the cell after degradation is shown in the ESI,† Fig. S15, where a degradation center is highlighted. In addition to the Br/I ratio, the high-temperature operational stability also depends on the composition of the organic cations.$^{78}$ For instance, the catastrophic degradation onset began earlier for the MAPbI$_3$:MABr (2.5 mg ml$^{-1}$) cell stressed at 80 °C, and the degradation features are similar to what was observed for FAPbI$_3$:MABr (10 mg ml$^{-1}$) (ESI,† Fig. S16 and S17).

Since the operational stability depends on both the organic cations and halide anions,$^{46,78,79}$ simultaneous engineering of organic cations and halide anions is expected to yield more stable perovskite solar cells. As shown in the ESI,† Fig. S18–S20, (Cs,FAPb)(I,Br)$_3$ based perovskite solar cells with absorber bandgaps ranging from 1.7 to 1.82 eV demonstrate promising operational stability even in ambient air. The superior operational features are similar to what was observed for FAPbI$_3$:MABr (10 mg ml$^{-1}$) (ESI,† Fig. S16 and S17).

So far, the stability tests are performed on perovskite prepared by a hybrid thermal evaporation/spin coating method. To verify that the observed degradation pattern is independent of the specific device architecture and layer stacks (perovskite composition and preparation method, charge selective layers, and TCO) employed in this study, we conduct a 1000 hour HLS experiment on perovskite solar cells using a Cs$_{0.17}$FA$_{0.83}$Pb(I$_{0.83}$Br$_{0.17}$)$_3$ absorber prepared by an anti-solvent method, and featuring a different transparent top contact made of C$_6$O/SnO$_2$/ITO/MgF$_2$. The detailed preparation procedure can be found elsewhere.$^{85}$ As shown in the ESI,† Fig. S21, the Cs$_{0.17}$-FA$_{0.83}$Pb(I$_{0.83}$Br$_{0.17}$)$_3$ perovskite absorber is more stable than MAPbI$_3$:MABr (20 mg ml$^{-1}$) and FAPbI$_3$:MABr (10 mg ml$^{-1}$) under the same HLS conditions. However, we still observe the same circular degradation pattern in Cs$_{0.17}$-FA$_{0.83}$Pb(I$_{0.83}$Br$_{0.17}$)$_3$ perovskite solar cells, particularly in the cell stressed under open circuit voltage conditions. The degradation pattern remains the same when replacing a solution processed PTAA hole transporting layer with magnetron sputtered NiO (ESI,† Fig. S22). These results demonstrate that the degradation pattern reported here is independent of the charge selective contact, perovskite absorber composition and preparation method, and TCO, suggesting the generality of the I$_2$-vapor-
assisted degradation mechanism in iodide containing semi-transparent perovskite solar cells.

**Conclusions**

We report an I$_2$ vapor-assisted self-propagating degradation mechanism in formamidinium–lead-iodide based perovskite solar cells stressed under operational conditions at 80 °C under an N$_2$ atmosphere. At high operational temperature, the degradation initiates primarily from the perovskite absorber interior instead of the perovskite/charge-selective layer interfaces or cell edges. The release of I$_2$ vapor appears as the main degradation driver. After an initial release either from traces of PbI$_2$ or from the perovskite itself, I$_2$ deteriorates the neighboring perovskite, releasing more I$_2$ and self-sustaining the degradation, which propagates across the active area. We show that the degradation pattern is independent of the perovskite composition and preparation method, charge selective layers, and top transparent contact, suggesting the universality of this I$_2$ vapor-assisted degradation mechanism in iodide containing organometal halide perovskites. Overall, our results present new insights into the degradation mechanisms of perovskite solar cells operating under long-term light soaking conditions at high temperatures. In view of designing photo- and

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**Fig. 7** Operational stability of FAPbI$_3$:MABr (20 mg ml$^{-1}$) solar cells. (a and b) Photographs of the cell before (a) and after (b) 320 hours MPP operation at 80 °C under a 500 mbar N$_2$ atmosphere. (c) The corresponding electroluminescence (EL) image of the same cell. (d) The photovoltaic parameters of the cell during 320 hours MPP operation at 80 °C under a 500 mbar N$_2$ atmosphere.
thermally-stable perovskite single junction and perovskite-based tandem photovoltaics, we demonstrate that incorporating more Br and/or Cs to reduce the MA⁺ and iodine content improves the operational stability of perovskite solar cells.

Methods

Perovskite solar cell fabrication

Perovskite solar cells were grown on commercial indium tin oxide (ITO) coated glass (sheet resistance: 8 Ω sq⁻¹, Zhuhai Kaivo Optoelectronics, P. R. China). The ITO glass was washed by hand first and then subjected to a soap and de-ionized water sonication bath at 85 °C, each for 15 min. The ITO glass was then dried by blowing nitrogen and used for solar cell processing without additional ozone treatment. The hole transporting layer was prepared by spin coating 30 μl of PTAA (Sigma-Aldrich) solution (5 mg ml⁻¹ in toluene doped with 1 wt% F4-TCNQ (97%, Sigma-Aldrich)) at 6000 rpm for 45 s on a 2.5 × 2.5 cm² substrate, followed by thermal annealing at 100 °C for 10 min. Afterwards, a ~200 nm PbI₂ (ultra dry, 99.999%, Alfa Aesar) compact film was thermally evaporated onto the rotating PTAA/ITO/glass without intentional heating. The deposition rate was controlled within 1–1.5 Å s⁻¹.

For PbI₂ deposition, the samples were transferred into a glovebox (Sigma-Aldrich) solution (5 mg ml⁻¹ in isopropanol) was porting layer was prepared by spin coating 30 μl of FAI solution (65 mg ml⁻¹ in isopropanol) was first spread on the PbI₂ surface, and then rotation to 6000 rpm was immediately started, which lasted for 45 s. The as-deposited films were annealed at 150 °C for 10 min. After cooling, the starting absorber FAPbI₃ was spin coated with various concentrations of MABr at 6000 rpm for 45 s to induce the exchange of organic cations and halides. Afterwards, the absorbers were annealed at 100 °C for 1 h under a chlorobenzene vapor atmosphere.

For the electron transporting layer, 30 μl of PCBM (PC₆₁BM, 99.5%, Solenne BV, Netherlands) solution (20 mg ml⁻¹ in chlorobenzene) was spin coated at 5000 rpm for 45 s, followed by 60 min annealing at 100 °C with cells covered by a Petri dish in the presence of 10 μl chlorobenzene. After cooling, 30 μl of undoped ZnO nanoparticles (2.7 wt% (crystalline ZnO dissolved in isopropanol), particle size: 10–15 nm, Sigma-Aldrich) were spin coated on top of the PCBM at 4000 rpm for 45 s. The ZnO nanoparticles were dried at 100 °C for 60 s to evaporate the solvent. Finally, the samples were coated with a ZnO:Al front contact by RF-magnetron sputtering and a Ni/Al (50 nm/4000 nm) metallic grid by e-beam evaporation. Finally, all cells were covered with a 105 nm MgF₂ anti-reflection coating deposited by e-beam evaporation. Single cells were defined by mechanical scribing down to the back ITO contact.

EL. Electroluminescence (EL) images were recorded by putting the solar cell in forward bias, while monitoring the applied voltage and the terminal current (2 V and 30 s acquisition time). The luminescence was measured using a high resolution digital B/W CCD camera ORCA-ER from Hamamatsu.

PL. Photoluminescence (PL) measurements were performed on full perovskite devices, and the laser was set to continuous wave mode at about 77 W cm⁻² with a spot diameter of ~50 μm. The spectrally integrated luminescence decay was measured using a Picoquant PMA-C 192 M photomultiplier tube and a Picoquant TimeHarp 260 digitizing system with a 50 ps time channel width.

ToF-SIMS. Time-of-flight secondary ion mass spectrometry (ToF-SIMS) measurements were performed on a ToF-SIMS.3 instrument from IONTOF, Germany, operated in spectral mode using a 25 keV Bi⁺ primary ion beam with an ion current of 0.7 pA. A mass resolving power in the range of 7000–10 000 m/Δm was reached. For depth profiling, a 500 eV Cs⁺ sputter beam with a current of 28.77 nA was used to remove the material layer-by-layer in interlaced mode from a raster area of 300 μm × 300 μm. The mass-spectrometry was performed on an area of 100 μm × 100 μm in the center of the sputter crater. A low-energy electron flood gun was used for charge compensation.

XPS. X-ray photoelectron spectroscopy (XPS) measurements were performed using a Quantum 2000 from Physical Electronics using a monochromatized Al Kα source (1486.6 eV). The measurements were recorded in fixed analyzer transmission mode with an angle of emission of 45° and at an instrument base pressure of below 8 × 10⁻⁸ Pa. The work function of the instrument is calibrated regularly to a binding energy of 83.95 eV (FWHM = 0.8 eV) for the Au 4f7/2 peak. The linearity of the energy scale is checked according to ISO 15472. Spectra were recorded with a pass energy of E₉ = 29.5 eV and an energy step size of ΔE = 0.125 eV. After probing the pristine layers, Ar⁺ sputtering for 120 s at 500 eV was performed to obtain information from the subsurface. Due to pronounced charging of the samples, a manual charge correction has been applied to align the metallic Pb⁰ components of the Pb 4f₇/₂ core level at 136.8 eV.

XRD. X-ray diffraction (XRD) patterns were obtained in the Bragg–Brentano geometry by using a X′Pert PRO with θ–2θ scans (Cu-Kα1 radiation, λ = 1.5406 Å) from 10 to 60° (2θ) with a step interval of 0.0167°. In situ XRD. In situ X-ray diffraction (XRD) patterns were also obtained in the Bragg–Brentano geometry with a PANalytical X′Pert PRO diffractometer (Cu-Kα1 radiation, λ = 1.5406 Å) equipped with an Anton Paar XRK-900 furnace chamber with Be windows. The samples were heated with a heating ramp of 10 °C min⁻¹ up to 80 °C and 100 °C (measured with a thermocouple adjacent to the sample), while keeping the chamber flooded with N₂ at a flow rate of 50 scm. θ–2θ scans from 10 to 15° (0.006565° per step, 4990 s per scan) were repeatedly measured for 4 days.

SEM. Scanning electron microscopy (SEM) cross-sectional images of the full devices were investigated with a Hitachi S-4800 scanning electron microscope using a 5 kV acceleration voltage. A thin layer (~1 nm) of Pt was coated on top of the samples to avoid the charging effect. For the perovskite and PbI₂ layers, the SEM top view morphology and cross-sectional images were acquired with a JEOL JSM-7500F FE using a 2 kV acceleration voltage and 62 μA current.

STEM EDX. Thin lamellae for transmission electron microscopy characterization were prepared using the conventional
focused ion beam (FIB) lift-out method using a Zeiss NVision 40 SEM/FIB workstation. The samples were thinned down to their final thickness with a final Ga+ voltage of 5 kV to reduce surface damage. The samples were then quickly transferred in the air (<2 min) to an FEI Osiris transmission electron microscope, which was operated at 200 kV with a scanning TEM beam current of 250 pA. Energy dispersive X-ray spectroscopy maps were recorded with a dwell time of 400 μs over 512 × 512 pixels (corresponding to doses of 5–350 pA nm⁻² depending on the resolution of the EDX maps), and quantified using the Cliff-Lorimer method⁸⁶ with the Bruker Esprit software. While the FIB sample preparation is known to modify the crystallography of metal halide perovskites on the nanometer scale by creating PbI₂ nanodomains,⁹,⁸⁷ the method is most suited to maintain the overall morphology of the layer stack and does not alter the distribution of elements on the >10 nm scale (except where re-deposition of material occurs due to the presence of pores, indicated by arrows in Fig. 4c). Furthermore, it should be noted that the pore fraction is overestimated in the FIB cross section of the degraded sample (Fig. 3c–e) due to the preferential sputtering of the perovskite regions not in direct contact with the top electrode and hence directly in the line of sight of the gallium ions. The electron doses involved during the acquisition of the STEM EDX maps led to amorphization⁸⁸ of the absorber and a slight loss of halides due to knock-on damage,⁸⁷ but not an overall change in microstructure.

**TGA-MS.** Thermogravimetric analysis-mass spectrometry (TGA-MS) experiments were conducted on a Netzsch STA449 F3 Jupiter DSC/TG apparatus coupled with a Netzsch QMS 403 mass spectrometer. The samples were heated from 30 to 400 °C at 5 K min⁻¹ and held at 400 °C for 30 min under a helium flow, which served as a carrier gas for the mass spectrometer. The samples (~6.5 mg) were scratched off the ITO substrate inside an Ar-filled glovebox and handled in sealed aluminum crucibles. A small hole was made in the crucible lid just before the measurement to allow the gases to escape.

**Solar cell characterization**

The current density–voltage characteristics of perovskite solar cells were measured using an ABA class solar simulator and Keithley 2400 source meter. The illumination intensity was calibrated to 1000 W m⁻² using a certified single crystalline silicon solar cell. The substrate temperature was kept at 25 °C using a Peltier element. The J–V measurements were performed in both forward (from −0.5 V to 1.2 V) and reverse (from 1.2 V to −0.5 V) directions separately without any pre-treatment (e.g. holding at forward bias for a certain time, etc.). The step size was set to 20 mV and the scan velocity varied from 18 to 190 mV s⁻¹. The external quantum efficiency of the cells was measured using a lock-in amplifier. The probing beam was generated by a chopped white source (900 W, halogen lamp, 260 Hz) and a dual grating monochromator. The beam size was adjusted to ensure that the illumination area was fully inside the cell area. The shading effect of the metallic grid was taken into account by including the middle grid line in the illuminated area. A certified single crystalline silicon solar cell was used as the reference cell. White light bias was applied during the measurement with a halogen bias lamp. The steady-state efficiency as a function of time was recorded using a maximum power point tracker, which adjusts the applied voltage in order to reach the maximum power point (perturb and observe algorithm). The starting voltage was set to 0.1 V.

**Heat light soaking (HLS)**

The long-term stability of perovskite solar cells was studied in a home-made stress chamber under controlled illumination intensity, temperature, and atmosphere. Specifically, un-encapsulated perovskite devices were placed on a copper plate at 80 °C and kept at the maximum power point (MPP) under continuous 1 sun illumination intensity using a white LED array. The stress chamber was maintained with a 500 mbar N₂ atmosphere during the stability test.

**Data availability statements**

The data that support the plots within this paper and other findings of this study are available from the corresponding author upon reasonable request.

**Contributions**

F. F., C. B., A. N. T., and S. B. designed and coordinated the research and experiments. F. F. fabricated the perovskite solar cells, and performed most of the characterization. S. P. performed the EL and PL measurements. Q. J. performed the TEM measurements and data analysis. J. S. P. and M. R. performed the in situ XRD measurements. M. K. performed the SIMS depth profiling, and C. A. conducted the XPS experiments. J. W. and P. F. helped with the UV-vis spectrometry and SEM top view measurements. L. D. conducted the TGA-MS measurements and analysis. A. P., T. M., and S. N. conducted the long-term stability tests of solution processed perovskite solar cells. F. F. with the help of Q. J. wrote the manuscript with inputs from all co-authors.

**Conflicts of interest**

There are no conflicts to declare.

**Acknowledgements**

Financial funding from the Swiss National Science Foundation (SNF)-NRP70, PV2050 (project No. 407040_153976 and 407040_153916), the Sinergia Episode (CRSII5_171000), SNF-NanoTera, Bridge Power (176552) and the Swiss Federal Office of Energy (SYNERGY: 20NA21_150950), as well as the Competence Center for Energy and Mobility, is gratefully acknowledged. M. K. acknowledges the funding from the Swiss National Science Foundation (Grant No. CR23I2-162828).
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